# Multichannel Capacitance to Voltage Converter for Pressure Sensor Front-end

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# Abstract

A multichannel CV converter circuit for a capacitive pressure sensor is proposed. Sampling technique, which eliminates amplifier blocks and reduces time constant of the output low pass filter, improves operation power and speed. Two channel CV converter has been fabricated with 0.18  $\mu$ m CMOS, and confirmed its performance and power of 0.63 mW/channel.

#### 1. Introduction

Pressure sensors are widely used in various applications and key issues for further market expansion are low cost and miniaturization, particularly in the consumer fields. Flexible sheet-like structure is another requirement for the application with human contacts such as medical area [1].

We have developed a flexible capacitive pressure sensor with conductive silicone rubber and polyethylene terephthalate (PET) sheet [2]. The sensor has the following advantages: simple structure, low cost, thin and small outline, and multichannel capability. A low power and high speed capacitance to voltage (CV) converter circuit is necessary to take the advantages of the sensor.

In this study, a low power multichannel channel CV converter circuit, which utilizes sampling techniques, is proposed. 2 channel CV converter has been fabricated with a standard 0.18  $\mu$ m CMOS and confirmed the performance.

# 2. Sensor Structure and Conventional CV Converter

Fig. 1 shows a schematic cross section and a photograph of a flexible capacitive pressure sensor. A movable conductive rubber electrode and a facing silver electrode printed on a PET sheet form a capacitance, which changes with the displacement of the movable electrode.



Fig. 1 A schematic cross section and a photograph of a flexible capacitive pressure sensor [2].

Fig. 2 shows a conventional CV converter circuit, which consists of three blocks of CV conversion, amplifier, and output [3].  $V_{IN}$  and its inverted input pulses are supplied to the sensors  $C_1$  and  $C_2$ , respectively. The difference charge stored in  $C_1$  and  $C_2$  are transferred to  $C_f$ , and the output  $V_{AMP1}$  is expressed as  $V_{AMP1} = V_r + (C_1 - C_2)V_{IN} / C_f$ . The pulsed output of  $V_{AMP1}$  is amplified and supplied to the output block of RC low pass filter, and is smoothed as the CV converter output  $V_{OUT}$ , which is proportional to the difference between  $C_1$  and  $C_2$ . Relatively large output current of the amplifier and time constant of the low pass filter for the sufficiently stable output increase the power consumption and response time, which should be improved for multichannel applications.

### 3. Design of Low Power Multichannel CV Converter

Fig. 3 shows a proposed 2 channel CV converter circuit. The circuit from  $V_{IN}$  to  $V_{AMP1}$  is same as the conventional circuit. Since  $V_{AMP1}$  gives the proper output voltage periodically with  $V_{IN}$ , a sampling technique at the appropriate timing can extract the desired output only, and thus the amplifier block can be eliminated. In addition, it is



Fig. 2 Conventional single channel CV converter circuit [3].



Fig. 3 Proposed 2 channel CV converter circuit.



Fig. 4 HSPICE simulation result of  $V_{AMP1}$  and sampling signals  $V_{SW01}/V_{SW02}$ , which capture the proper voltage of  $V_{AMP1}$ .



Fig. 5 Simulated waveforms of  $V_{\text{OUT}}$  for the conventional and proposed circuits.



Fig. 6 Photographs of circuit blocks of 2 channel CV converter.

possible to reduce the time constant of the RC low pass filter significantly, and to use an on-resistance of the switching transmission gates as the resistor of the RC filter.

Fig. 4 shows a HSPICE simulation result of  $V_{AMP1}$  and sampling signals  $V_{SWO1}/V_{SWO2}$ , which capture the proper voltage of  $V_{AMP1}$ . Two different sampling periods of  $V_{SWO1}/V_{SWO2}$  can separate the 2 channel outputs. Fig. 5 shows simulated waveforms of  $V_{OUT}$  for our conventional and proposed circuits. The power and the response time become about 1/5 and 1/8, respectively. The proposed circuit is scalable and can easily expands channel counts. We also have designed an 8 channel CV converter, which can share a CV conversion block among the 8 channels.

# 4. Measurement Results of the Fabricated LSI

Fig. 6 shows photographs of circuit blocks of 2 channel CV converter fabricated with a standard 0.18 µm CMOS. Fig. 7 shows measured results of  $V_{AMP1}$  for  $C_{1(4)} = 20 - 23$  pF keeping  $C_{2(3)}=20$  pF. Although it gives slight overshoots around the transient region,  $V_{AMP1}$  holds the proper voltage during the sampling periods. Fig. 8 shows CV converter output  $V_{OUT}$  for  $\Delta C (= C_{1(3)} - C_{2(4)}) = \pm 3$  pF. Although the transient change of  $V_{OUT}$  cannot be observed in our setup, measured results of  $V_{OUT}$  agree with the simulation.  $V_{OUT}$  is proportional to  $\Delta C$  in the range of 0 through 7 pF as shown in Fig. 9. The two channel CV converter LSI is successfully demonstrated and Table I summarizes the performance.



Fig. 7 Measured results of VAMP1 for various C1 for fixed C2.



Fig. 8 CV converter output  $V_{OUT}$  for  $\Delta C = \pm 3$  pF.



Fig. 9 Capacitance change  $\Delta C$  dependence of V<sub>OUT</sub>.

Table I Performance summary of the proposed circuit

	Proposed (2CH)	Our Conv. (2CH)	Ref. [4]
V <sub>DD</sub> (V)	3.3 V	3.3 V	3.3 V
Process	0.18 µm CMOS	0.18 μm CMOS	0.6 μm CMOS
Circuit Area	0.13 mm <sup>2</sup>	0.27 mm <sup>2</sup>	0.71 mm <sup>2</sup>
Power consumption	0.63 mW	3.5 mW	2.7 mW
Response Time	0.3 ms	2.4 ms	1.0 ms

#### 5. Conclusions

A two channel CV converter circuit for flexible pressure sensors has been proposed and fabricated with a standard 0.18  $\mu$ m CMOS. The output is proportional to the difference of sensor capacitances up to 7 pF. Power consumption of the circuit is 0.63 mW, which is reduced by 80% from our conventional circuit. Response time of 0.3 ms is sufficiently fast for the further multichannel systems.

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